

#### NOT RECOMMENDED FOR NEW DESIGN USE DMP2045U



**DMG3415U** 

#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON) max</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C	
2017	$42.5 \text{m}\Omega$ @ $V_{GS} = -4.5 \text{V}$	-4.0A	
-20V	71mΩ @ V <sub>GS</sub> = -1.8V	-2.0A	

## **Description**

This new generation MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## **Applications**

- **DC-DC Converters**
- Power Management Functions

### **Features**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 3kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- **PPAP Capable (Note 4)**

#### Mechanical Data

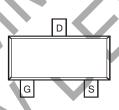
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



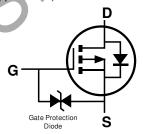


SOT23

Top Viev







**Equivalent Circuit** 

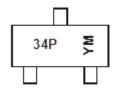
## Ordering Information (Note 5)

F	art Number	Compliance	Case	Packaging
	MG3415U-7	Standard	SOT23	3,000/Tape & Reel
DI	MG3415UQ-7	Automotive	SOT23	3,000/Tape & Reel
D	MG3415U-13	Standard	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
  2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## Marking Information



34P = Product Type Marking Code YM or  $\overline{Y}M$  = Date Code Marking Y or  $\overline{Y}$  = Year (ex: F = 2018) M = Month (ex: 9 = September)

Date Code Key

Year	201	8	2019		2020	20	21	2022		2023	2	2024
Code	F		G		Н			J		K		L
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



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### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	$V_{DSS}$	-20	V
Gate-Source Voltage	$V_{GSS}$	±8	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = -4.5V	I <sub>D</sub>	-4.0 -3.5	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I <sub>DM</sub>	-30	Α

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 6)	P <sub>D</sub>	0.9	W
Thermal Resistance, Junction to Ambient (Note 6)	R <sub>0</sub> JA	139	°C/W
Thermal Resistance, Junction to Case (Note 6)	ReJC	32	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

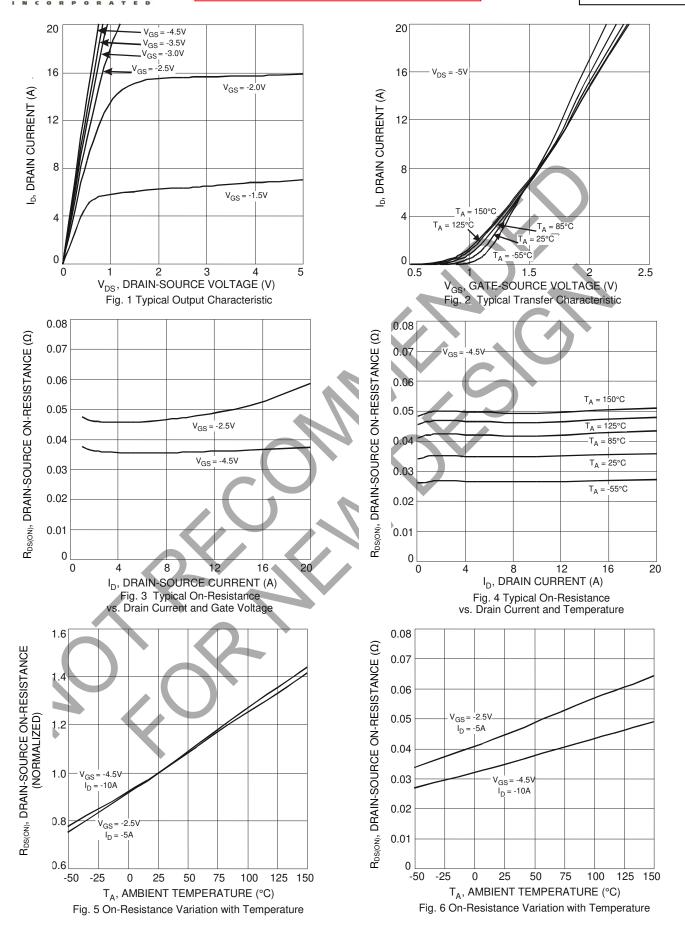
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20	-	- `	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-1	μΑ	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	+	±10	μΑ	$V_{GS} = \pm 8.0V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.3	-0.55	-1.0	V	$V_{DS} = V_{GS}$ , $I_D = -250\mu A$	
		$\rightarrow$	31	42.5		$V_{GS} = -4.5V, I_D = -4.0A$	
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>		40	53	mΩ	$V_{GS} = -2.5V, I_D = -3.5A$	
			51	71		$V_{GS} = -1.8V, I_D = -2.0A$	
Forward Transfer Admittance	g <sub>FS</sub>	1	3	_	S	$V_{DS} = -5V, I_{D} = -4A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C <sub>iss</sub>		294	_	pF		
Output Capacitance	Coss		104	_	pF	$V_{DS} = -10V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	1	25	_	pF	1 – 1.5141112	
Gate Resistance	$R_g$	_	250	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	Qg	_	9.1	_	nC	45)/ // 40)/	
Gate-Source Charge	$Q_{gs}$	1	1.5	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V$ $I_{D} = -4A$	
Gate-Drain Charge	$Q_{gd}$	1	1.7	_	nC	10 - 471	
Turn-On Delay Time	t <sub>D(ON)</sub>		71	_	ns		
Turn-On Rise Time	t <sub>R</sub>		117	_	ns	$V_{DS} = -10V, V_{GS} = -4.5V,$	
Turn-Off Delay Time	t <sub>D(OFF)</sub>		795		ns	$R_D = 2.5\Omega$ , $R_G = 3.0\Omega$ , $I_D = -1A$	
Turn-Off Fall Time	t <sub>F</sub>	_	393	_	ns		

Notes:

- 6. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
- $7. \ Short \ duration \ pulse \ test \ used \ to \ minimize \ self-heating \ effect.$
- 8. Guaranteed by design. Not subject to production testing.

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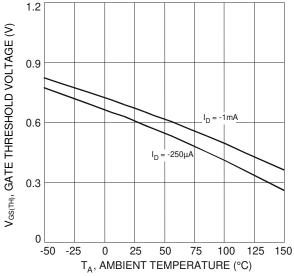
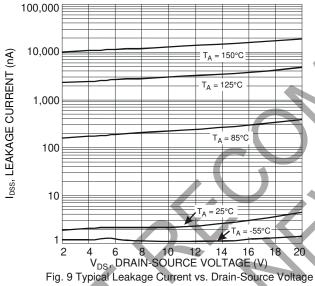
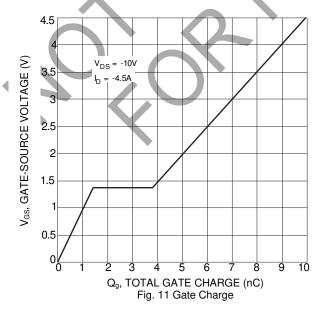
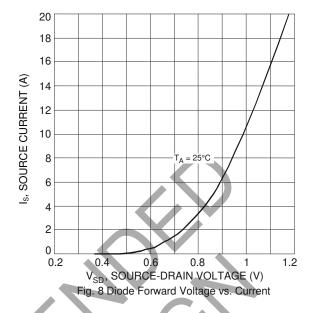


Fig. 7 Gate Threshold Variation vs. Ambient Temperature







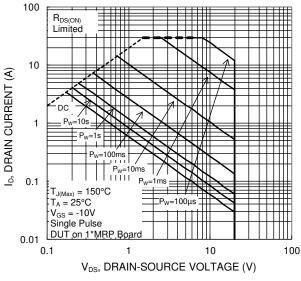
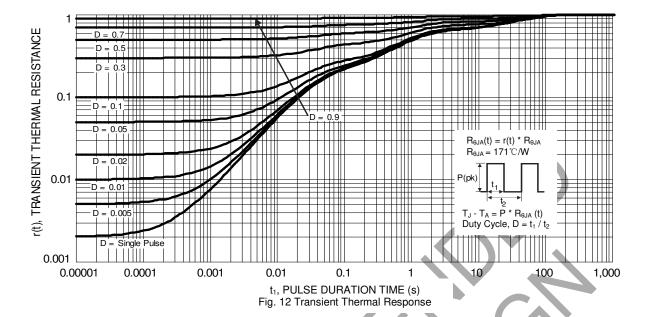


Fig. 10 SOA, Safe Operation Area



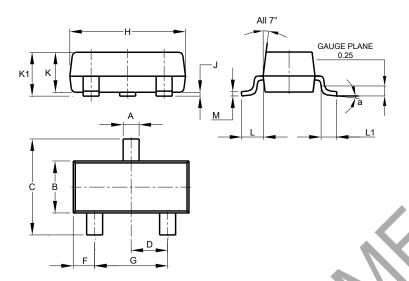


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## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT23

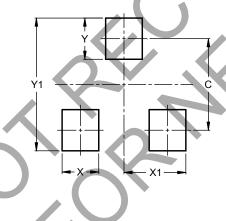


SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

## SOT23



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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